

isc N-Channel MOSFET Transistor

IPD35N10S3L-26

• FEATURES

- Drain Current – $I_D = 35A$ @ $T_c=25^\circ C$
- Drain Source Voltage-
 - : $V_{DSS} = 100V$ (Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 24m\Omega$ (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

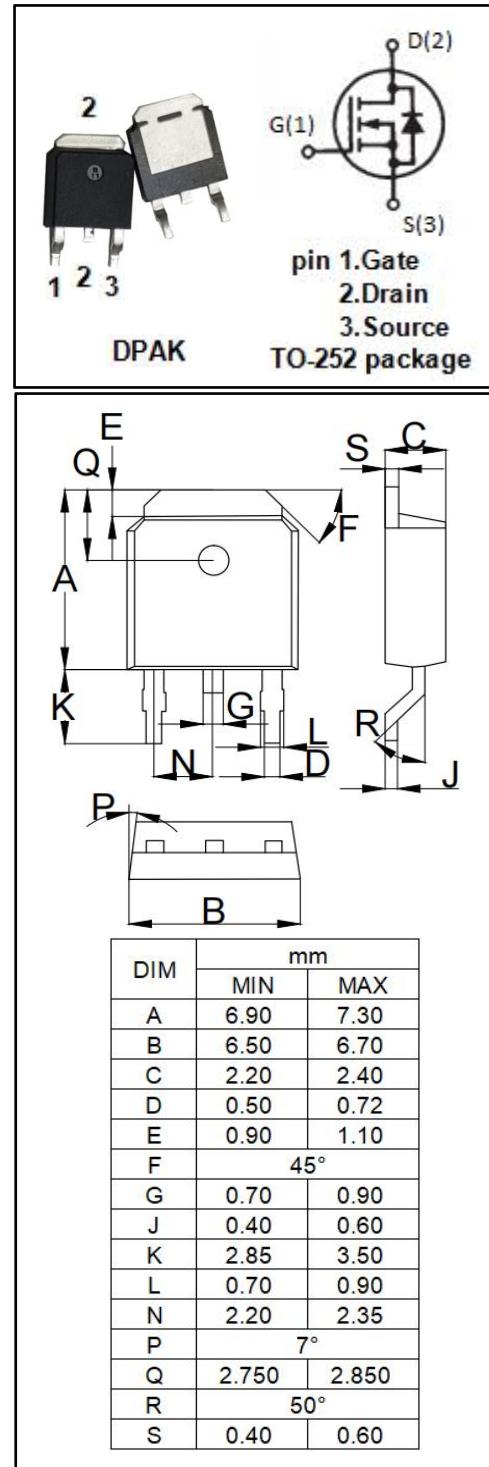
- Ultra Low On-resistance
- Fast Switching

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	100	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	35	A
I_{DM}	Drain Current-Single Pulsed	140	A
P_D	Total Dissipation @ $T_c=25^\circ C$	71	W
T_j	Max. Operating Junction Temperature	-55~175	°C
T_{stg}	Storage Temperature	-55~175	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Channel-to-case thermal resistance	2.1	°C/W



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ELECTRICAL CHARACTERISTICS

 $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{I}_\text{D}=1\text{mA}$	100	--	V
$\text{V}_{\text{GS(th)}}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}; \text{I}_\text{D}=39\text{ }\mu\text{A}$	1.2	2.4	V
$\text{R}_{\text{DS(on)}}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}=10\text{V}; \text{I}_\text{D}=35\text{A}$	--	24	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$\text{V}_{\text{GS}}= \pm 20\text{V}$	--	± 0.1	μA
I_{DSS}	Drain-Source Leakage Current	$\text{V}_{\text{DS}}=80\text{V}; \text{V}_{\text{GS}}= 0\text{V}$	--	0.1	μA
V_{SD}	Diode forward voltage	$\text{I}_\text{S}=35\text{A}, \text{V}_{\text{GS}} = 0\text{V}$	--	1.2	V

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